

153CMQ...SERIES-G SCHOTTKY RECTIFIER

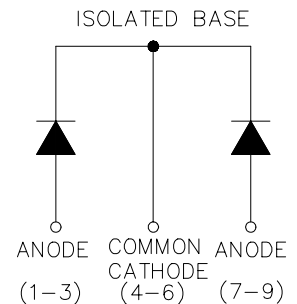
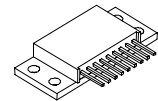
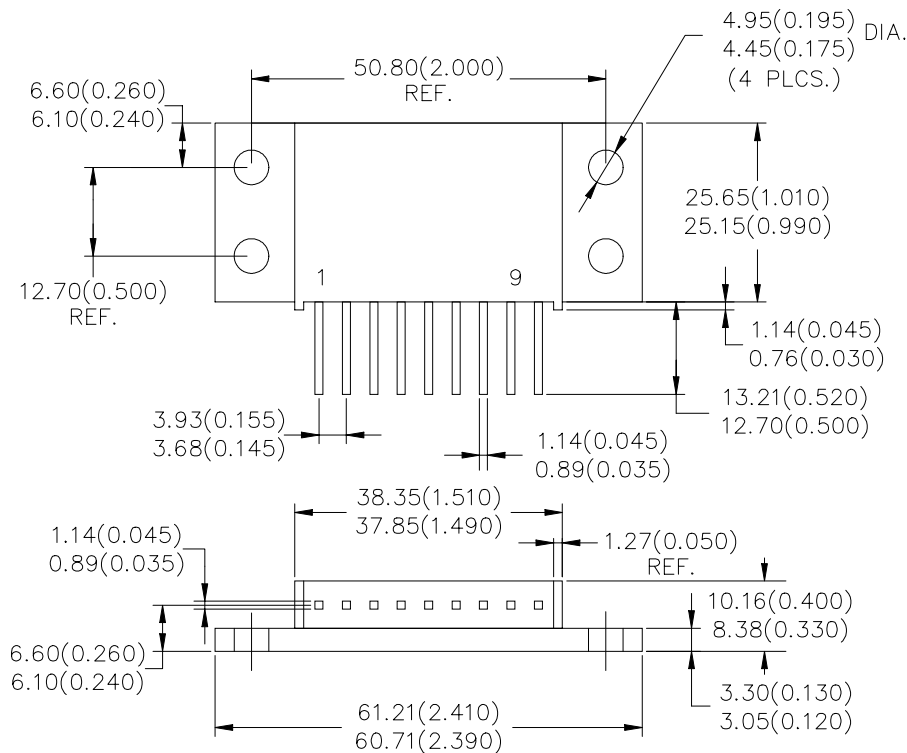
Applications:

- Switching power supply • Free-Wheeling diodes • Reverse battery protection • Converters

Features:

- 175°C T_J operation
- Isolated heatsink
- Multiple leads per terminal for high frequency, high current PC board mounting
- Low profile, high current package
- Center tap module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Green Products in Compliance with the RoHS Directive

Mechanical Dimensions: In Inches / mm



TO-249(9 pin)

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	80	V
			100	
			153CMQ080-G	
			153CMQ100-G	
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle @ $T_C = 90^\circ\text{C}$, rectangular wave form	150	A
Max. Peak One Cycle Non-Repetitive Surge Current (per leg)	I_{FSM}	8.3 ms, half Sine pulse	860	A
Non-Repetitive Avalanche Energy (per leg)	E_{AS}	$T_J = 25^\circ\text{C}$, $I_{AS} = 1\text{ A}$, $L = 30\text{ mH}$	15	mJ
Repetitive Avalanche Current (per leg)	I_{AR}	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical	1	A

Electrical Characteristics:

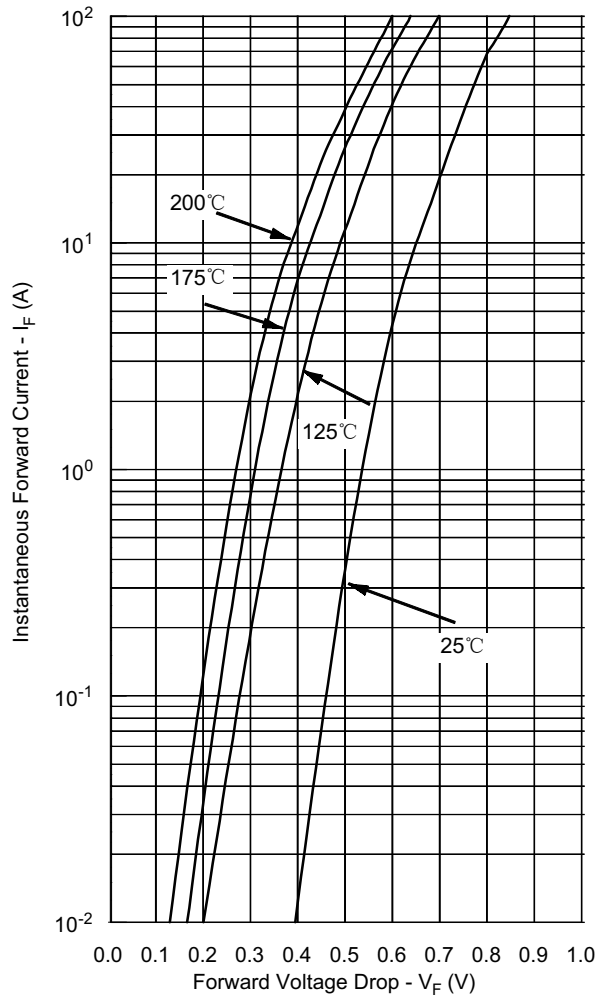
Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg) *	V_{F1}	@ 75 A, Pulse, $T_J = 25^\circ\text{C}$	0.96	V
		@ 150 A, Pulse, $T_J = 25^\circ\text{C}$	1.19	
	V_{F2}	@ 75 A, Pulse, $T_J = 125^\circ\text{C}$	0.80	V
		@ 150 A, Pulse, $T_J = 125^\circ\text{C}$	0.99	
Max. Reverse Current (per leg) *	I_{R1}	@ $V_R = \text{rated } V_R$ $T_J = 25^\circ\text{C}$	1.5	mA
		@ $V_R = \text{rated } V_R$ $T_J = 125^\circ\text{C}$	20	
Max. Junction Capacitance (per leg)	C_T	@ $V_R = 5\text{ V}$, $T_C = 25^\circ\text{C}$ $f_{SIG} = 1\text{ MHz}$	1400	pF
Typical Series Inductance (per leg)	L_S	Measured lead to lead 5 mm from package body	9.2	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/ μs

* Pulse Width < 300 μs , Duty Cycle <2%

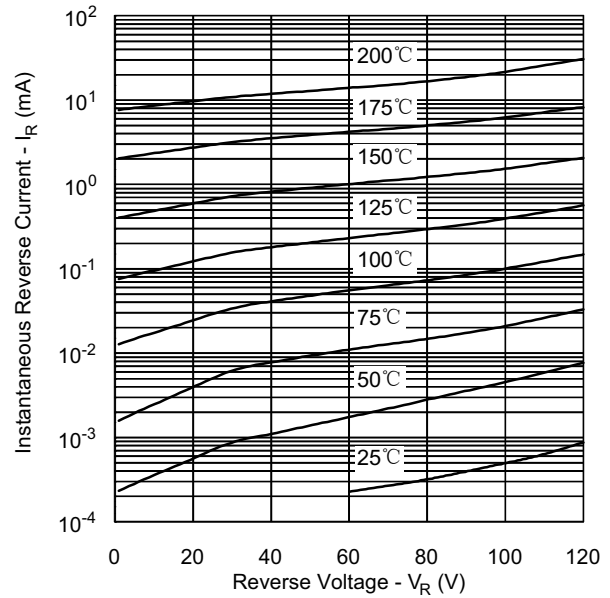
Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	T_J	-	-55 to +175	$^\circ\text{C}$
Max. Storage Temperature	T_{stg}	-	-55 to +175	$^\circ\text{C}$
Maximum Thermal Resistance Junction to Case (per leg)	$R_{\theta JC}$	DC operation	1.0	$^\circ\text{C/W}$
Maximum Thermal Resistance Junction to Case (per device)	$R_{\theta JC}$	DC operation	0.50	$^\circ\text{C/W}$
Maximum Thermal Resistance, Case to Heat Sink	$R_{\theta CS}$	Mounting surface, smooth and greased	0.10	$^\circ\text{C/W}$
Approximate Weight	wt	-	56	g
Mounting Torque	T_M	-	40 (min) 58 (max)	Kg-cm
Case Style	TO-249(9 pin)			

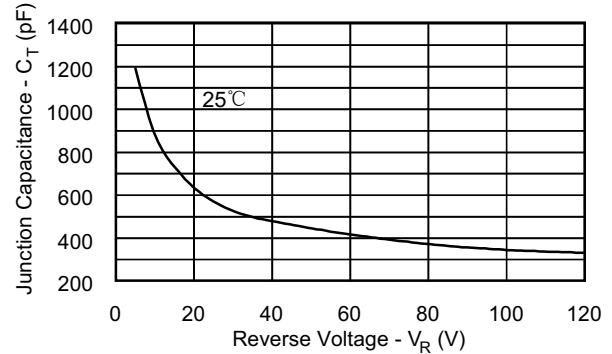
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



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